



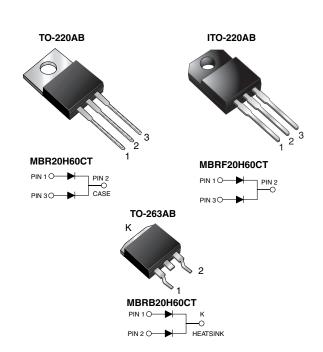
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Vishay General Semiconductor

RoHS

Dual Common Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 10 A				
V_{RRM}	60 V				
I _{FSM}	150 A				
V_{F}	0.61 V				
I _R	100 μΑ				
T _J max.	175 °C				
Package	TO-220AB, ITO-220AB, TO-263AB				
Diode variations	Common cathode				

FEATURES

- Power pack
- Guardring for overvoltage protection
- · Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHE3_A
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified ("_X" denotes revision code, e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER			MBR20H60CT	UNIT		
Maximum repetitive peak reverse voltage			60			
Working peak reverse voltage		V_{RWM}	60	V		
Maximum DC blocking voltage		V_{DC}	60			
Maximum average forward rectified current (fig. 1)	total device	1	20	Α		
	per diode	I _{F(AV)}	10			
Non-repetitive avalanche energy per diode at 25 °C, I _{AS} =	4 A, L = 10 mH	E _{AS}	80	mJ		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150	А		
Peak repetitive reverse surge current per diode at t _p = 2.0 μs, 1 kHz		I _{RRM}	0.5			
Peak non-repetitive reverse energy (8/20 µs waveform)			10	mJ		
Electrostatic discharge capacitor voltage Human body model: C = 100 pF, R = 1.5 k Ω		V _C	25	kV		
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs		
Operating junction and storage temperature range		T_J , T_{STG}	-65 to +175	°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V_{AC}	1500	V		

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MBR20H60CT, MBRF20H60CT, MBRB20H60CT

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		MBR20H60CT		UNIT
	STIMBOL			TYP.	MAX.	UNII
Maximum instantaneous forward voltage per diode	V _F ⁽¹⁾	I _F = 10 A	T _C = 25 °C	=	0.71	
		I _F = 10 A	T _C = 125 °C	0.57	0.61	V
		I _F = 20 A	T _C = 25 °C	=	0.85	
		I _F = 20 A	T _C = 125 °C	0.68	0.71	
Maximum reverse current per diode	I _R ⁽²⁾	I _R ⁽²⁾ Rated V _R	T _J = 25 °C	=	100	μΑ
			T _J = 125 °C	2.0	12	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT	
Typical resistance, junction to case per diode	$R_{ heta JC}$	2.0	4.0	2.0	°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR20H60CT-E3/45	1.85	45	50/tube	Tube	
ITO-220AB	MBRF20H60CT-E3/45	1.99	45	50/tube	Tube	
TO-263AB	MBRB20H60CT-E3/45	1.35	45	50/tube	Tube	
TO-263AB	MBRB20H60CT-E3/81	1.35	81	800/reel	Tape and reel	
TO-220AB	MBR20H60CTHE3/45 (1)	1.85	45	50/tube	Tube	
ITO-220AB	MBRF20H60CTHE3/45 (1)	1.99	45	50/tube	Tube	
TO-263AB	MBRB20H60CTHE3/45 (1)	1.35	45	50/tube	Tube	
TO-263AB	MBRB20H60CTHE3/81 (1)	1.35	81	800/reel	Tape and reel	
TO-263AB	MBRB20H60CTHE3_A/P (1)	1.35	Р	50/tube	Tube	
TO-263AB	MBRB20H60CTHE3_A/I (1)	1.35	I	800/reel	Tape and reel	

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

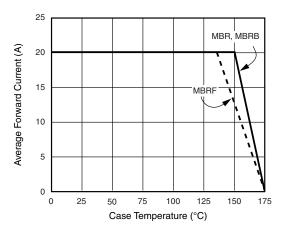


Fig. 1 - Forward Current Derating Curve (Total)

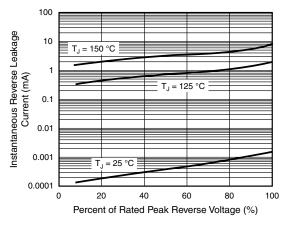


Fig. 4 - Typical Reverse Characteristics Per Diode

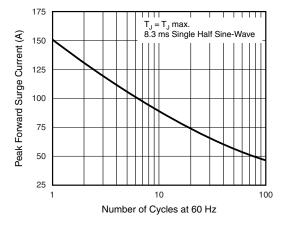


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

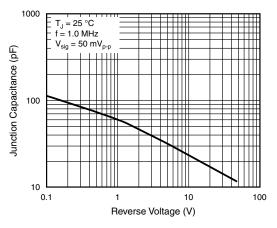


Fig. 5 - Typical Junction Capacitance Per Diode

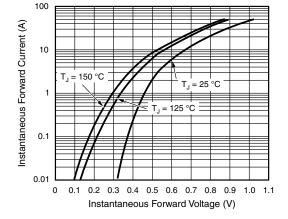


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

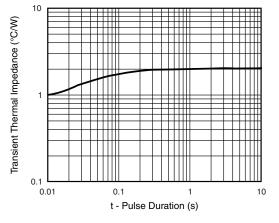


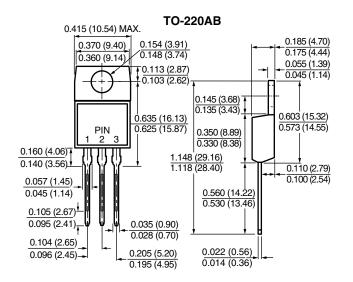
Fig. 6 - Typical Transient Thermal Impedance Per Diode

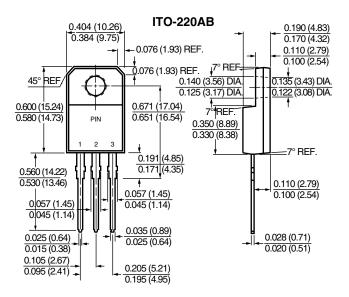


MBR20H60CT, MBRF20H60CT, MBRB20H60CT

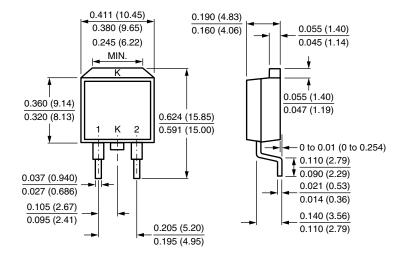
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

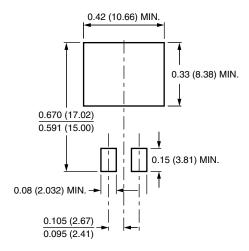




TO-263AB



Mounting Pad Layout





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